

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	(delimit dilimitation delimiting delimited) same (resistor resistive) same (implant implantation implanting) same (wafer substrate board support)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:05
L2	4	(delimit dilimitation delimiting delimited) same (resistor resistive) same (implant implantation implanting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:16
L3	4	2 and (@ad<"20020930" @rlad<"20020930")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:29
L4	4	2 and @ad<"20020930"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:18
L5	982	(resistor resistive).near3 (implant implantation implanting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:29
L6	789	5 and @ad<"20020930"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:16
L7	0	discrete near (resistor resistive) near3 (implant implantation implanting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:17
L8	0	discrete near2 (resistor resistive) near3 (implant implantation implanting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:17
L9	1	discrete near2 (resistor resistive) near10 (implant implantation implanting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:19

EAST Search History

L10	7	discrete near2 (resistor resistive) same (implant implantation implanting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:18
L11	7	10 and @ad<"20020930"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:19
L12	32	discrete near2 (resistor resistive) near2 (region area)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:28
L13	30	12 and @ad<"20020930"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:22
L14	110	discrete near2 (resistor resistive) near2 (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:21
L15	83	14 and @ad<"20020930"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:29
L16	75	15 not 13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:22
L17	11060	(resistor resistive) near2 (region area)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:28
L18	203	(resistor resistive) near2 (region area) near3 (implant implantation implanting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:29
L19	159	18 and @ad<"20020930"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:29

EAST Search History

L20	164	18 and (@ad<"20020930" @rlad<"20020930")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/29 15:29
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